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MM74HC4051 • MM74HC4052 • MM74HC4053 8-Channel Analog Multiplexer • Dual 4-Channel Analog Multiplexer • **Triple 2-Channel Analog Multiplexer**

General Description

The MM74HC4051, MM74HC4052 and MM74HC4053 multiplexers are digitally controlled analog switches implemented in advanced silicon-gate CMOS technology. These switches have low "on" resistance and low "off" leakages. They are bidirectional switches, thus any analog input may be used as an output and vice-versa. Also these switches contain linearization circuitry which lowers the on resistance and increases switch linearity. These devices allow control of up to ±6V (peak) analog signals with digital control signals of 0 to 6V. Three supply pins are provided for $V_{\mbox{CC}},$ ground, and $V_{\mbox{EE}}.$ This enables the connection of 0– 5V logic signals when $V_{\mbox{\scriptsize CC}}\,{=}\,5V$ and an analog input range of $\pm 5V$ when $V_{FF} = 5V$. All three devices also have an inhibit control which when HIGH will disable all switches to their off state. All analog inputs and outputs and digital inputs are protected from electrostatic damage by diodes to $V_{\mbox{\scriptsize CC}}$ and ground.

MM74HC4051: This device connects together the outputs of 8 switches, thus achieving an 8 channel Multiplexer. The binary code placed on the A, B, and C select lines determines which one of the eight switches is "on", and connects one of the eight inputs to the common output.

MM74HC4052: This device connects together the outputs of 4 switches in two sets, thus achieving a pair of 4-channel multiplexers. The binary code placed on the A, and B select lines determine which switch in each 4 channel section is "on", connecting one of the four inputs in each section to its common output. This enables the implementation of a 4-channel differential multiplexer.

MM74HC4053: This device contains 6 switches whose outputs are connected together in pairs, thus implementing a triple 2 channel multiplexer, or the equivalent of 3 singlepole-double throw configurations. Each of the A, B, or C select lines independently controls one pair of switches, selecting one of the two switches to be "on".

Features

- Wide analog input voltage range: ±6V
- Low "on" resistance:
- 50 typ. $(V_{CC} V_{EE} = 4.5V)$
- 30 typ. $(V_{CC} V_{EE} = 9V)$
- Logic level translation to enable 5V logic with ±5V analog signals
- Low quiescent current: 80 μA maximum (74HC)
- Matched Switch characteristic

Ordering Code:

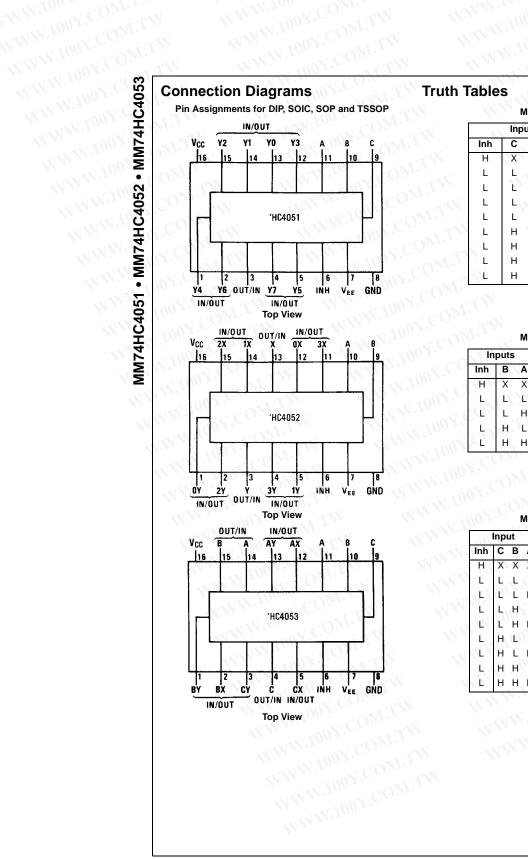
Order Number	Package Number	Package Description
MM74HC4051M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC4051WM	M16B	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
MM74HC4051SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC4051MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC4051N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-0010.300" Wide
MM74HC4052M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC4052WM	M16B	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
MM74HC4052SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC4052MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC4052N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-0010.300" Wide
MM74HC4053M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
MM74HC4053WM	M16B	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
MM74HC4053SJ	M16D	16-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
MM74HC4053MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
MM74HC4053N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-0010.300" Wide

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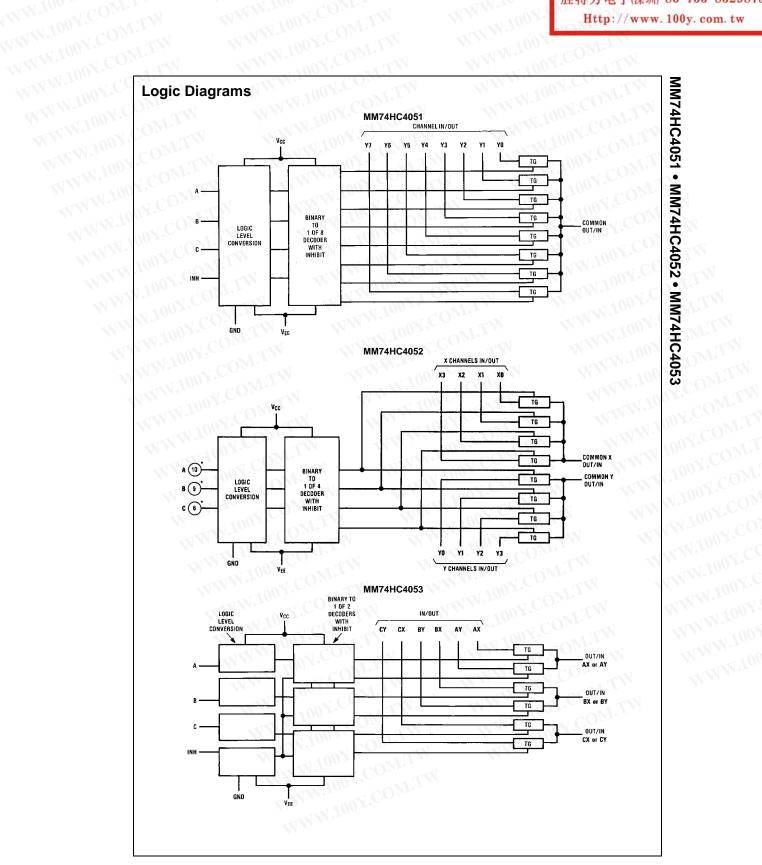


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-	Inp	ut	-0	"ON"
Inh	С	В	Α	Channel
Н	Х	Х	Х	None
L	L	ςĽ.	E	Y0
L	L	L	н	Y1
L	L	н	L	Y2
L	L	н	H	Y3
L	н	L	L	Y4
L	н	L	H	Y5
L	н	н	L	Y6
Ń.	н	H	н	Y7

In	puts		"ON" Channels						
nh	В	Α	Х	Y					
H	Х	Х	None	None					
L.	Ľ	L	0X	OY					
L	L	Н	1X	1Y					
L	H.	L	2X	2Y					
L	н	H	3X	3Y					

- 01	Inp	ut		"ON	" Chan	nels
Inh	С	в	Α	С	b	а
H	Х	Х	Х	None	None	None
Ľ	L,	Ŀ.	L	сх	BX	AX
L.	L	L	н	СХ	вх	AY
L	L	Н	L	СХ	BY	AX
Ų.	Ł	н	н	CX	BY	AY
L,	н	Ľ	L	CY	BX	AX
L	н	L	н	CY	BX	AY
L	н	н	Ľ	CY	BY	AX
L	н	н	н	CY	BY	AY



WWW.100Y.COM.TW WWW.100Y.COM.TW WWW.100Y.COM.TW LODY.COM.TW Absolute Maximum Ratings(Note 1) (Note 2)

Recommended Operating Conditions

	Supply Voltage (V _{CC})	-0.5 to +7.5V	
	Supply Voltage (V _{EE})	+0.5 to -7.5V	Supply Voltage (V _{CC})
	Control Input Voltage (VIN)	-1.5 to V _{CC} +1.5V	Supply Voltage (V _{EE})
	Switch I/O Voltage (VIO)	V_{EE} –0.5 to V_{CC} +0.5V	DC Input or Output Volt
	Clamp Diode Current (I _{IK} , I _{OK})	±20 mA	(V _{IN} , V _{OUT})
-	Output Current, per pin (I _{OUT})	±25 mA	Operating Temperature
-	V_{CC} or GND Current, per pin (I _{CC})	±50 mA	Input Rise or Fall Times
	Storage Temperature Range (T _{STG})	-65°C to +150°C	$(t_r, t_f) V_{CC} = 2.0 V$
	Power Dissipation (P _D)		$V_{CC} = 4.5V$
	(Note 3)	600 mW	$V_{CC} = 6.0V$
	S.O. Package only	500 mW	Note 1: Absolute Maximum R
	Lead Temperature (T _L)		age to the device may occur.
	(Soldering 10 seconds)	260°C	Note 2: Unless otherwise spect Note 3: Power Dissipation ter 12 mW/°C from 65°C to 85°C.
			12 11117 0 11011 00 0 10 00 0.

	Min	Max	Units
Supply Voltage (V _{CC})	2	6	V
Supply Voltage (V _{EE})	0	-6	V
DC Input or Output Voltage			
(V _{IN} , V _{OUT})	0	V _{CC}	V
Operating Temperature Range (T _A)	-40	+85	°C
Input Rise or Fall Times			
$(t_r, t_f) V_{CC} = 2.0 V$		1000	ns
$V_{CC} = 4.5V$		500	ns
$V_{CC} = 6.0V$		400	ns
Note 1: Absolute Maximum Ratings are those age to the device may occur.	values be	eyond whi	ch dam-

ecified all voltages are referenced to ground. emperature derating — plastic "N" package:

DC Electrical Characteristics (Note 4)

Symbol	Parameter	-1	Conditions	VEE	V _{cc}	T _A =	25°C	$T_A = -40$ to $85^{\circ}C$	$T_A = -55$ to $125^{\circ}C$	Units
Symbol	Parameter		Conditions	*EE	▼CC	Тур	1.1	Guaranteed	Limits	Units
VIH	Minimum HIGH Level		N WIL		2.0V	CU	1.5	1.5	1.5	V
	Input Voltage			x11	4.5V		3.15	3.15	3.15	V
	N.COm		WW	11.	6.0V		4.2	4.2	4.2	V
VIL	Maximum LOW Level	1.1		N.	2.0V		0.5	0.5	0.5	V
	Input Voltage		VW I		4.5V		1.35	1.35	1.35	V
	N.100 CO			ALX.	6.0V		1.8	1.8	1.8	V
R _{ON}	Maximum "ON" Resista	ance	$V_{INH} = V_{IL}, I_S = 2.0 \text{ mA}$	GND	4.5V	40	160	200	240	Ω
	Maximum "ON" Resistance (Note 5) Maximum "ON" Resistance Matching Maximum Control Input Current Maximum Quiescent		$V_{IS} = V_{CC}$ to V_{EE}	-4.5V	4.5V	30	120	150	170	Ω
	1001.0		(Figure 1)	-6.0V	6.0V	20	100	125	140	Ω
	W. Long C		$V_{INH} = V_{IL}, I_S = 2.0 \text{ mA}$	GND	2.0V	100	230	280	320	Ω
	1001.		$V_{IS} = V_{CC}$ or V_{EE}	GND	4.5V	40	110	140	170	Ω
	WW.L		(Figure 1)	-4.5V	4.5V	20	90	120	140	Ω
	100 L		1.1	-6.0V	6.0V	15	80	100	115	Ω
R _{ON}	Maximum "ON" Resista	ance	V _{CTL} = V _{IL}	GND	4.5V	10	20	25	25	Ω
	Matching		VIS = VCC to GND	-4.5V	4.5V	5	10	15	15	Ω
	WW		WTIE	-6.0V	6.0V	5	10	12	15	Ω
I _{IN}	Maximum Control	-16	V _{IN} = V _{CC} or GND			N V	±0.1	±1.0	±1.0	μA
	Input Current		$V_{CC} = 2 - 6V$				110	Mo		
I _{CC}	Maximum Quiescent	1	$V_{IN} = V_{CC}$ or GND	GND	6.0V	NV.	8	80	160	μA
	Supply Current		$I_{OUT} = 0 \ \mu A$	-6.0V	6.0V		16	160	320	μΑ
I _{IZ}	Maximum Switch "OFF	"	V _{OS} = V _{CC} or V _{EE}	GND	6.0V	NN	±60	±600	±600	nA
	Leakage Current		VIS = VEE or VCC	-6.0V	6.0V		±100	±1000	±1000	nA
	(Switch Input)		V _{INH} = V _{IH} (Figure 2)					1001.0	WTI	
I _{IZ}	Maximum Switch	N.Y.	$V_{IS} = V_{CC}$ to V_{EE}	GND	6.0V		±0.2	±2.0	±2.0	μA
	"ON" Leakage	HC4051	$V_{INH} = V_{IL}$	-6.0V	6.0V		±0.4	±4.0	±4.0	μA
	Current	N.L	(Figure 3)				W	N.L	10 MA	
			V _{IS} = V _{CC} to V _{EE}	GND	6.0V		±0.1	±1.0	±1.0	μA
		HC4052	V _{INH} = V _{IL} (Figure 3)	-6.0V	6.0V		±0.2	±2.0	±2.0	μA
			$V_{IS} = V_{CC}$ to V_{EE}	GND	6.0V		±0.1	±1.0	±1.0	μA
	1	HC4053	V _{INH} = V _{IL} (Figure 3)	-6.0V	6.0V		±0.1	±1.0	±1.0	μA

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DC Elec	trical Characteristics (Continued)	

Symbol	Parameter		Conditions	VEE	Vcc	T _A =	25°C	$T_A = -40$ to $85^{\circ}C$	$T_A = -55$ to $125^{\circ}C$	Units
Cynnoor	T urumeter		Conditions			Тур		Guaranteed	Limits	onito
IZ	Maximum Switch	-15	$V_{OS} = V_{CC} \text{ or } V_{EE}$	GND	6.0V	M	±0.2	±2.0	±2.0	μA
	"OFF" Leakage	HC4051	V _{IS} = V _{EE} or V _{CC}	-6.0V	6.0V		±0.4	±4.0	±4.0	μA
	Current (Common Pin)		V _{INH} = V _{IH}	COL				WWW.	LON.CO	20
	M.T.M.		$V_{OS} = V_{CC} \text{ or } V_{EE}$	GND	6.0V		±0.1	±1.0	±1.0	μA
	N/m	HC4052	V _{IS} = V _{EE} or V _{CC}	-6.0V	6.0V		±0.2	±2.0	±2.0	μA
	M.L		$V_{INH} = V_{IH}$	1	N		7	TAT	N.100	OM
	W		$V_{OS} = V_{CC} \text{ or } V_{EE}$	GND	6.0V	1	±0.1	±1.0	±2.0 ±4.0 ±1.0	μA
	COM.	HC4053	V _{IS} = V _{EE} or V _{CC}	-6.0V	6.0V		±0.1	±1.0	±1.0	μA
	WT.		$V_{INH} = V_{IH}$	0.1.					1001.	

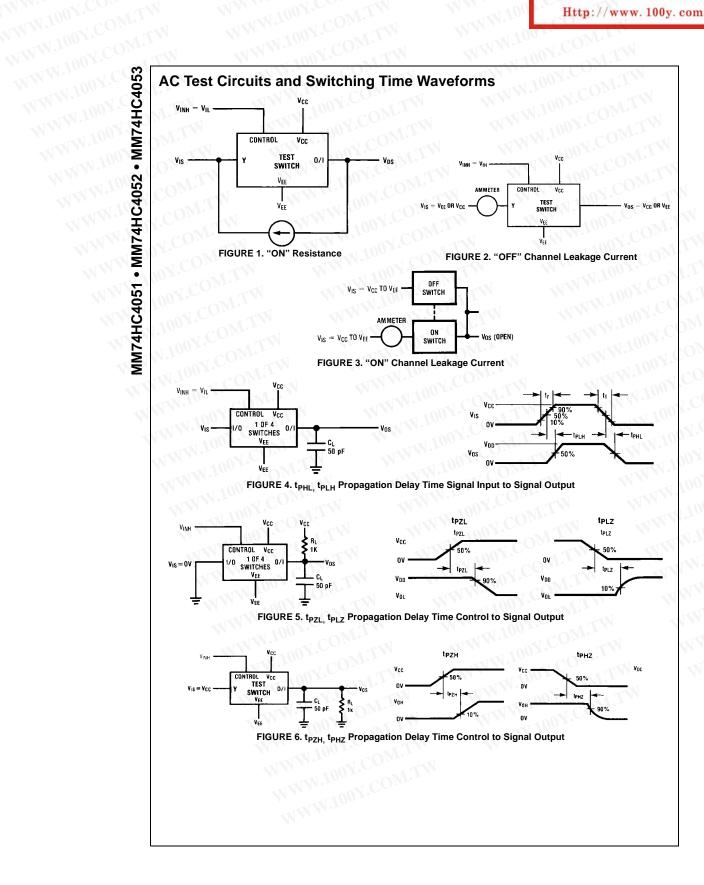
Note 4: For a power supply of 5V ±10% the worst case on resistances (R_{ON}) occurs for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at V_{CC} = 5.5V and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current occur for CMOS at the higher voltage and so the 5.5V values should be used.

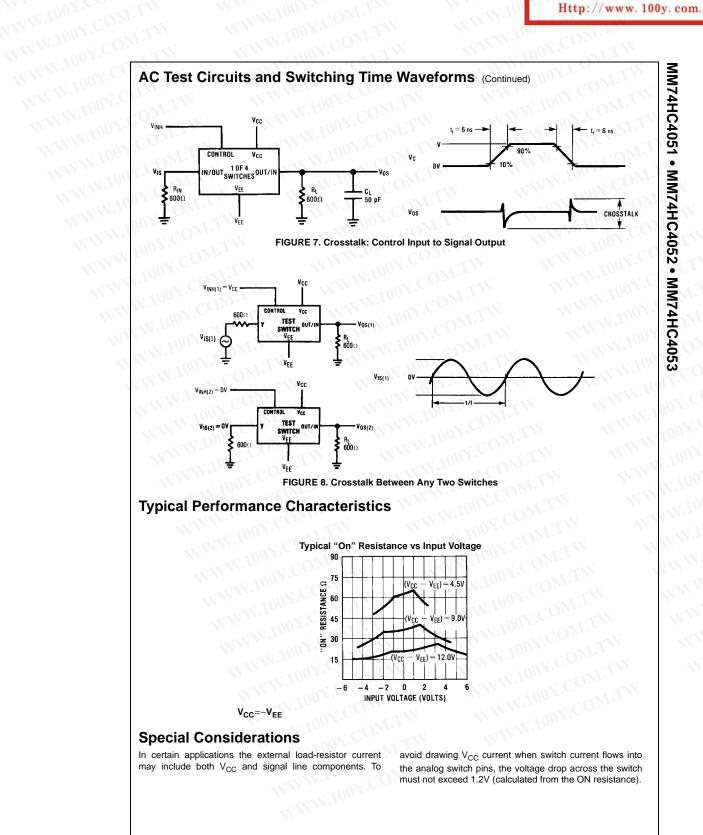
Note 5: At supply voltages (V_{CC}-V_{EE}) approaching 2V the analog switch on resistance becomes extremely non-linear. Therefore it is recommended that these devices be used to transmit digital only when using these supply voltages.

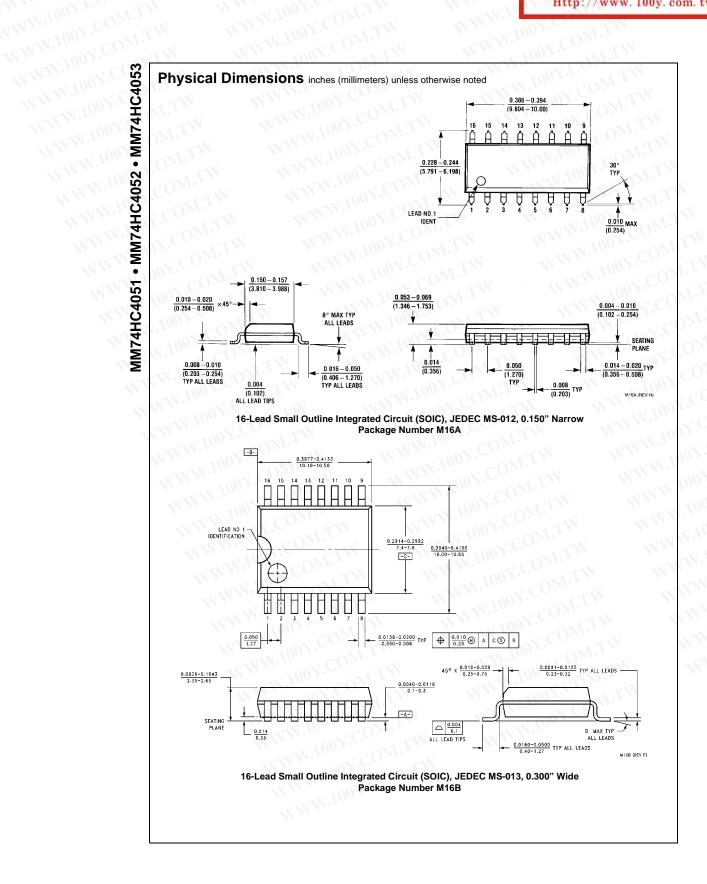
AC Electrical Characteristics

Symbol	0V–6.0V, V _{EE} = 0V–6V, C		~		0	T _A =	25°C	$T_A = -40 \text{ to } 85^{\circ}\text{C}$ $T_A = -55 \text{ to } 125^{\circ}\text{C}$		
100 - 01	Parameter	Conditions		V _{EE}	V _{cc}	Тур		Guaranteed Limits		Units
t _{PHL} , t _{PLH}	Maximum Propagation	Wr.	1	GND	2.0V	25	60	75	90	ns
	Delay Switch In to Out	1.1		GND	4.5V	5	12	15	18	ns
	AND Y.CO.	WTA		-4.5V	4.5V	4	8	12	14	ns
	W.IV TCC	Nr	KÎ.	-6.0V	6.0V	3	7	11	13	ns
t _{PZL} , t _{PZH}	Maximum Switch Turn	$R_L = 1 k\Omega$		GND	2.0V	92	355	435	515	ns
	"ON" Delay	OM.		GND	4.5V	N	69	87	103	ns
	1001.	M		-4.5V	4.5V	16	46	58	69	ns
WW.Loov.	COM		-6.0V	6.0V	15	41	51	62	ns	
t _{PHZ} , t _{PLZ}	Maximum Switch Turn	coN.		GND	2.0V	65	290	365	435	ns
	"OFF" Delay			GND	4.5V	28	58	73	87	ns
	W.IO	- CON		-4.5V	4.5V	18	37	46	56	ns
	VV 100			-6.0V	6.0V	16	32	41	48	ns
f _{MAX}	Minimum Switch		N. A.	GND	4.5V	30		V.COm	IIT	MHz
	Frequency Response	J		-4.5V	4.5V	35	NI1	No.		MHz
	20 log (V _I /V _O) = 3 dB	J.C.	Jun	N.		WW		N.CO.	WT -	-
	Control to Switch	$R_L = 600\Omega$,	$V_{IS} = 4 V_{PP}$	0V	4.5V	1080	N.		11.	mV
	Feedthrough Noise	f = 1 MHz,	$V_{IS} = 8 V_{PP}$	-4.5V	4.5V	250		1001.00	WT	mV
	W.	$C_L = 50 \text{ pF}$	-ON-	-			NT.	Los CC	N	
	Crosstalk between	$R_L = 600\Omega$,	$V_{IS} = 4 V_{PP}$	0V	4.5	-52		11001.	M.T.W	dB
	any Two Switches	f = 1 MHz	$V_{IS} = 8 V_{PP}$	-4.5V	4.5V	-50	AT N	N.L. av C	ON	dB
	Switch OFF Signal	$R_L = 600\Omega$,	$V_{IS} = 4 V_{PP}$	0V	4.5V	-42		100 1	-M.	dB
	Feedthrough	f = 1 MHz,	$V_{IS} = 8 V_{PP}$	-4.5V	4.5V	-44	VI.	N	COMM	dB
	Isolation	$V_{CTL} = V_{IL}$		1.1				W.100 F	COM-1	
THD	Sinewave Harmonic	$R_L = 10 \ k\Omega$,	$V_{IS} = 4 V_{PP}$	0V	4.5V	0.013		100		%
	Distortion	$C_{L} = 50 \text{ pF},$	$V_{IS} = 8 V_{PP}$	-4.5V	4.5V	0.008		W.W.	- CON-	%
	N/	f = 1 kHz	MY.C		W			100	1.00	
CIN	Maximum Control	N.	100	1024		5	10	10	10	pF
	Input Capacitance				(T)					
CIN	Maximum Switch	Input		CO_{2}		15				pF
	Input Capacitance	4051 Commo	on 👘		1.3	90				
		4052 Commo	on	I.CU	74-	45				
		4053 Commo	on			30				
CIN	Maximum Feedthrough Capacitance	WW				5				pF

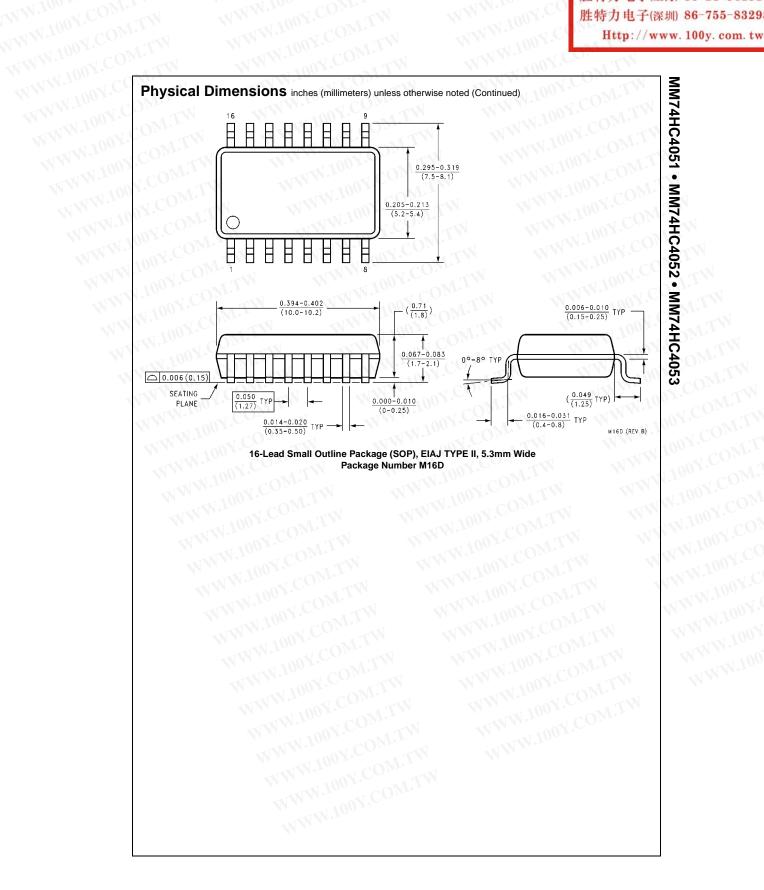
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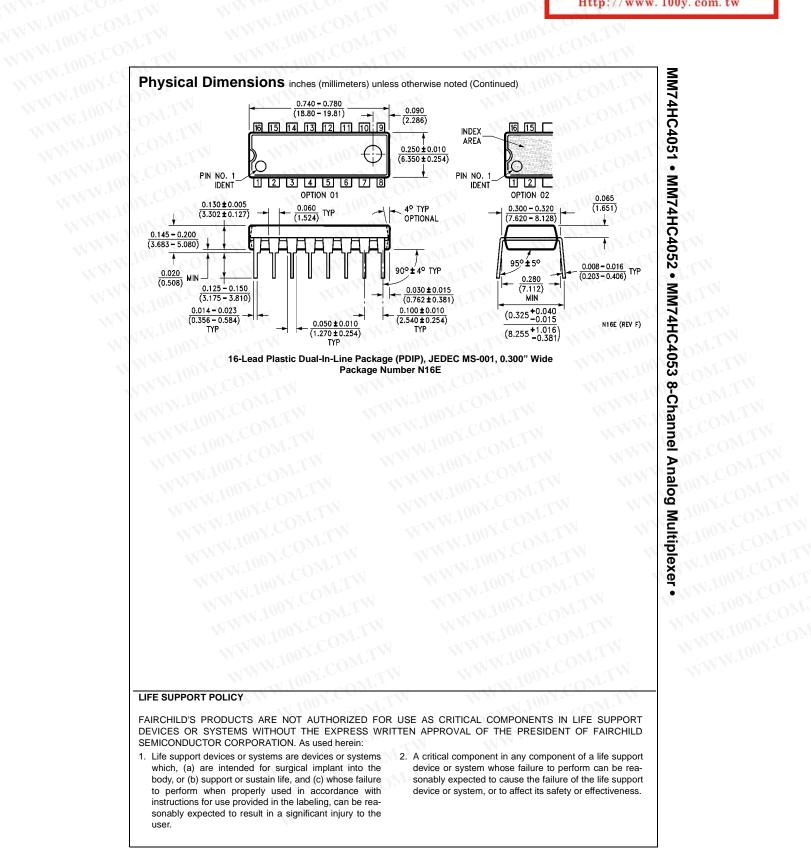


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WWW.100Y.COM.TW WWW.100Y.COM.TW WWW.100Y.COM.TW MM74HC4051 • MM74HC4052 • MM74HC4053 Physical Dimensions inches (millimeters) unless otherwise noted (Continued) 7.72 TYP. 4.16 TYP. DIMENSIONS METRIC ONLY (1.78 TYP) 5.0 ± 0.1 y.coM -A-9 0.42 TYP 16 0.65 TYP П LAND PATTERN RECOMMENDATION GAGE PLANE 6.4 0.25 4.4 ± 0.1 -B-3.2 SEATING PLANE 00-80- 0.6 ± 0.1 DETAIL A TYPICAL, SCALE: 40X △ 0.2 C B A 8 ALL LEAD TIPS PIN #1 IDENT. SEE DETAIL A - (0.90) □ 0.1 C A ALL LEAD TIPS 1.1 MAX TYP ¥. -c-0.10 ± 0.05 TYP 0.09-0.20 TYP ◄► 0.65 TYP 0.19 - 0.30 TYP \oplus 0.13 M A вS cS MTC16 (REV C) 16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC16 WWW.100Y WWW.100Y.COM.





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